Serial Number: 10/791,048

Filing Date: March 2, 2004

Title: LOCAL CONTROL OF UNDERFILL FLOW ON HIGH DENSITY PACKAGES, PACKAGES AND SYSTEMS MADE THEREWITH,

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AND METHODS OF MAKING SAME

Assignee: Intel Corporation

IN THE CLAIMS

Please amend the claims as follows:

- 1. (Original) An article comprising:
 - a mounting substrate;
 - a passive component site on the mounting substrate;
 - an active component site on the mounting substrate; and
- a fluid flow barrier disposed local to the passive component site and spaced apart from the active component site.
- 2. (Original) The article of claim 1, the mounting substrate including a first side and a second side, wherein the passive component site and the active component site are disposed in a solder mask on the first side, and wherein the fluid flow barrier is integral with the solder mask.
- 3. (Original) The article of claim 1, wherein the fluid flow barrier includes a sidewall and a floor, wherein the floor includes an electrically conductive material.
- 4. (Original) The article of claim 1, the mounting substrate including a first side and a second side, wherein the passive component site and the active component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, and wherein the trench describes a perimeter around the passive component site.
- 5. (Original) The article of claim 1, the mounting substrate including a first side and a second side, wherein the passive component site and the active component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the passive component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the active component site,

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and wherein the trench side that is adjacent and spaced apart from the active component site includes a non-linear boundary.

- 6. (Original) The article of claim 1, the mounting substrate including a first side and a second side, wherein the passive component site and the active component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the passive component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the active component site, wherein the trench side that is adjacent and spaced apart from the active component site includes a non-linear boundary, and wherein the non-linear boundary is selected from curvilinear, rectilinear, and combinations thereof.
- 7. (Original) The article of claim 1, wherein the passive component site is spaced apart a distance from the active component site in a range from about 5 mm to about 1 mm.
- 8. (Original) The article of claim 1, wherein the passive component site is spaced apart a distance from the active component site by about 1.7 mm.
- 9. (Original) The article of claim 1, further including at least one fluid flow barrier that is disposed general to the active component site.
- 10. (Original) The article of claim 1, wherein the at least one fluid flow barrier includes a trench with a dielectric floor.

Claims 11-28. (Canceleed)

29. (New) The article of claim 1, wherein the passive component site is one of a plurality of passive component sites.

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30. (New) The article of claim 1, wherein the passive component site is one of a plurality of passive component sites, and wherein at least one fluid flow barrier of the plurality of passive component sites presents a non-linear boundary toward the active component site.

- 31. (New) An article comprising:
 - a mounting substrate;
 - a first component site on the mounting substrate;
 - a second component site on the mounting substrate; and
- a fluid flow barrier disposed local to the first component site and spaced apart from the second component site.
- 32. (New) The article of claim 31, the mounting substrate including a first side and a second side, wherein the first component site and the second component site are disposed in a solder mask on the first side, and wherein the fluid flow barrier is integral with the solder mask.
- 33. (New) The article of claim 31, wherein the fluid flow barrier includes a sidewall and a floor, wherein the floor includes an electrically conductive material.
- 34. (New) The article of claim 31, the mounting substrate including a first side and a second side, wherein the first component site and the second component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, and wherein the trench describes a perimeter around the first component site.
- 35. (New) The article of claim 31, the mounting substrate including a first side and a second side, wherein the first component site and the second component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the first component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the second component site, and wherein the trench side that is adjacent and spaced apart from the second component site includes a non-linear boundary.

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36. (New) The article of claim 31, the mounting substrate including a first side and a second side, wherein the first component site and the second component site are disposed in a solder mask on the first side, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the first component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the second component site, wherein the trench side that is adjacent and spaced apart from the second component site includes a non-linear boundary, and wherein the non-linear boundary is selected from curvilinear, rectilinear, and combinations thereof.

- 37. (New) The article of claim 31, wherein the first component site is spaced apart a distance from the second component site in a range from about 5 mm to about 1 mm.
- 38. (New) The article of claim 31, wherein the first component site is spaced apart a distance from the second component site by about 1.7 mm.
- 39. (New) The article of claim 31, further including at least one fluid flow barrier that is disposed general to the second component site.
- 40. (New) The article of claim 31, wherein the at least one fluid flow barrier includes a trench with a dielectric floor.
 - 41. (New) An article comprising:

a mounting substrate including a first side and a second side, wherein the first component site and the second component site are disposed in a solder mask on the first side;

a first component site on the mounting substrate;

a second component site on the mounting substrate; and

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a fluid flow barrier disposed local to the first component site and spaced apart from the second component site, and wherein the fluid flow barrier is integral with the solder mask.

- 42. (New) The article of claim 41, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the first component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the second component site, wherein the trench side that is adjacent and spaced apart from the second component site includes a non-linear boundary, and wherein the non-linear boundary is selected from curvilinear, rectilinear, and combinations thereof.
- 43. (New) The article of claim 41, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the first component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the second component site, wherein the trench side that is adjacent and spaced apart from the second component site includes a non-linear boundary, and wherein the non-linear boundary is a composite of rectilinear segments and curvilinear segments.
- 44. (New) The article of claim 41, wherein the fluid flow barrier is a trench in the solder mask, wherein the trench describes a perimeter around the first component site, wherein the perimeter includes a trench side that is adjacent and spaced apart from the second component site, wherein the trench side that is adjacent and spaced apart from the second component site includes a non-linear boundary including an angle, and wherein the angle is in a range from about 179° to about 91.
- 45. (New) The article of claim 41, wherein the first component site is one of a plurality of first component sites.

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(New) The article of claim 41, wherein the first component site is one of a 46. plurality of first component sites, and wherein at least one fluid flow barrier of the plurality of first component sites presents a non-linear boundary toward the second component site.